



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL31B225KOHNNWE

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 2.2 µF, 16V, ±10%, X7R, 1206

A. Samsung Part Number

<u>CL</u> <u>31</u> <u>B</u> <u>225</u> <u>K</u> <u>O</u> <u>H</u> <u>N</u> <u>N</u> <u>W</u> <u>E</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor						
2	Size	1206 (inch c	code) L: 3.2	± 0.2 mm	W:	1.6	± 0.2	mm
3	Dielectric	X7R	8	Inner electrode		Ni		
4	Capacitance	2.2 μF		Termination		Cu		
(5)	Capacitance	±10 %		Plating		Sn 10	0%	(Pb Free)
	tolerance		9	Product		Norm	al	
6	Rated Voltage	16 V	10	Special		Produ	ict for N	etwork application
7	Thickness	1.6 ± 0.2	mm 🕦	Packaging		Embo	ssed T	ype, 7" reel

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms					
Tan δ (DF)	0.035 max.						
Insulation	10,000Mohm or 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.					
Resistance	Whichever is Smaller						
Appearance	No abnormal exterior appearance	Microscope (×10)					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X7R						
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±15%)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120 ℃ for 10~30sec.)					
Resistance to	Capacitance change : within ±7.5%	Solder pot : 270±5℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition				
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change : within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.05 max	40±2℃, 90~95%RH, 500+12/-0hrs				
	IR: 500Mohm or 25Mohm ⋅ μF					
	Whichever is Smaller					
High Temperature	Capacitance change : within ±12.5%	With 200% of the rated voltage				
Resistance	Tan δ : 0.05 max	Max. operating temperature				
	IR: 1000Mohm or 50Mohm · μF					
	Whichever is Smaller	1000+48/-0hrs				
Temperature	Capacitance change : within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25°C				
		→ Max. operating temperature → 25°C				
		5 cycle test				

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}\text{C}$, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.